



60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
	69mΩ @ V _{GS} = 10V	14A
60V	100mΩ @ V _{GS} = 4.5V	12A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Power-Management Functions
- DC-DC Converters

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low Rds(ON)—Ensures Minimal On-State Losses
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Wettable Flank for Improved Optical Inspections
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

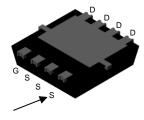
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 - https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMN6069SFVWQ)

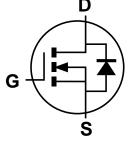
Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)

PowerDI3333-8 (SWP) (Type UX)







Top View

Pin1 Bottom View

Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN6069SFVW-7	PowerDI3333-8 (SWP) (Type UX)	2,000/Tape & Reel
DMN6069SFVW-13	PowerDI3333-8 (SWP) (Type UX)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

PowerDI is a registered trademark of Diodes Incorporated.



Marking Information



N69 = Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 21 = 2021)

WW = Week Code (01 to 53)

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	60	V		
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 5)	Steady State	T _A = +25°C T _A = +70°C	lo	4.0 3.2	А
Continuous Drain Current, V _{GS} = 10V (Note 6)	Steady State	$T_C = +25$ °C $T_C = +70$ °C	lo	14 11	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%	I _{DM}	56	Α		
Maximum Continuous Body Diode Forward Current	Is	4.0	Α		
Pulsed Source Current (380µs Pulse, Duty Cycle = 1	Ism	56	А		
Avalanche Current , L = 0.1mH	I _{AS}	12	Α		
Repetitive Avalanche Energy , L = 0.1mH	Eas	7.2	mJ		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	P_{D}	2.5	W	
Thermal Resistance, Junction to Ambient (Note 5) Steady State		R _{OJA}	50	°C/W
Total Power Dissipation (Note 6)	PD	32	W	
Thermal Resistance, Junction to Case (Note 6)	Steady State	R _{eJC}	3.9	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

lotes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).

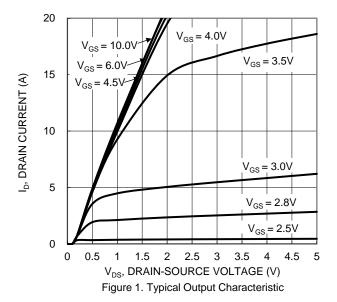


Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	60		_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current				1	μΑ	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	Igss			±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	1		3	٧	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	D		35	69	mΩ	$V_{GS} = 10V, I_{D} = 3A$	
Static Dialii-Source Off-Resistance	RDS(ON)	_	41	100		$V_{GS} = 4.5V, I_D = 2.4A$	
Diode Forward Voltage	VsD		0.8	1.1	V	$V_{GS} = 0V, I_{S} = 2.5A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		740		pF	V _{DS} = 30V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	40	_	pF		
Reverse Transfer Capacitance	Crss		28		pF		
Gate Resistance	Rg		2.2	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (VGS = 4.5V)	Qg	_	6.4	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	14	_	nC	7,, 20,7,1, 40,4	
Gate-Source Charge	Qgs	_	2.8	_	nC	$V_{DS} = 30V, I_{D} = 12A$	
Gate-Drain Charge	Q_{gd}	_	2.3	_	nC	1	
Turn-On Delay Time	t _{D(ON)}	_	3.6	_	ns		
Turn-On Rise Time	t _R		5.0	_	ns	$V_{DS} = 30V, I_{D} = 12A$ $V_{GS} = 10V, R_{G} = 6.0\Omega$	
Turn-Off Delay Time	tD(OFF)	_	12	_	ns		
Turn-Off Fall Time	tF	_	3.3	_	ns		
Body Diode Reverse Recovery Time	trr	_	11	_	ns	1 4 00 11/14 4000//	
Body Diode Reverse Recovery Charge	Qrr	_	5.1	_	nC	I _F = 1. 9A, di/dt = 100A/μs	

7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing. Notes:





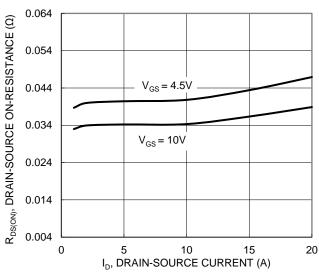


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

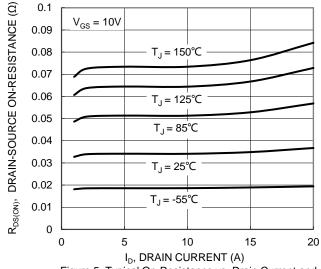


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

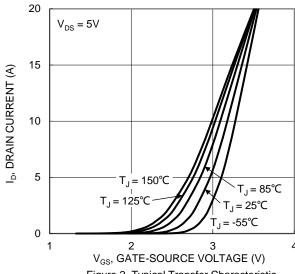


Figure 2. Typical Transfer Characteristic

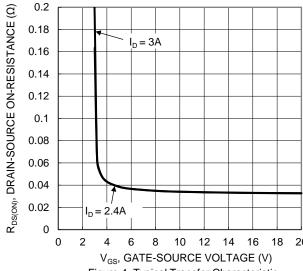


Figure 4. Typical Transfer Characteristic

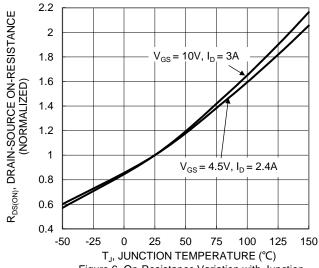
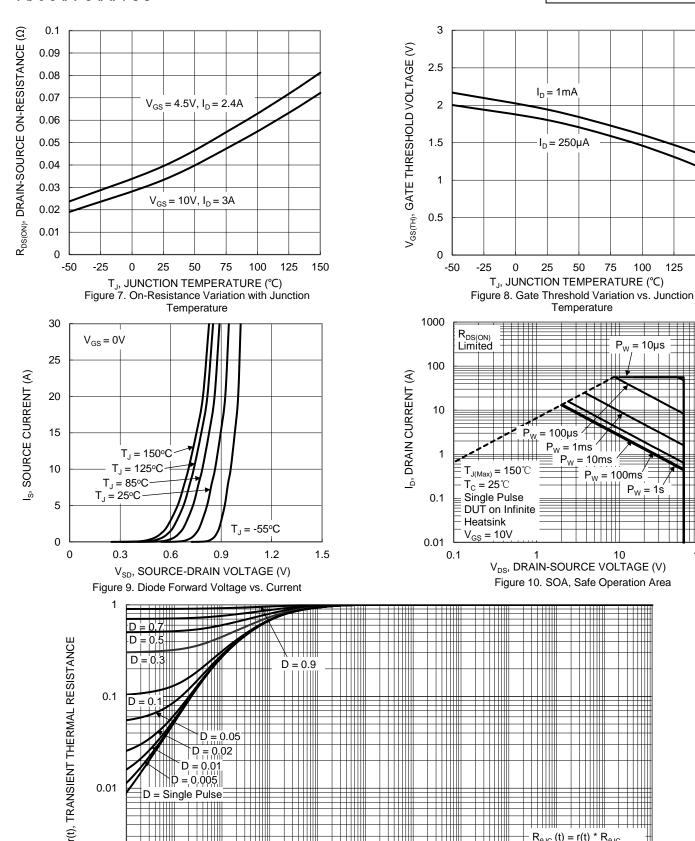


Figure 6. On-Resistance Variation with Junction Temperature

150

100





0.001

0.00001

0.0001

0.001

0.01

t1, PULSE DURATION TIME (sec) Figure 11. Transient Thermal Resistance 100000 1000000

$$\begin{split} R_{\theta JC} & (t) = r(t) * R_{\theta JC} \\ R_{\theta JC} & = 3.9 °C/W \\ \text{Duty Cycle, D} & = t1/t2 \end{split}$$

10000

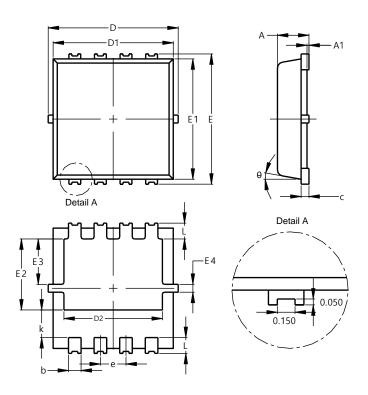
1000



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

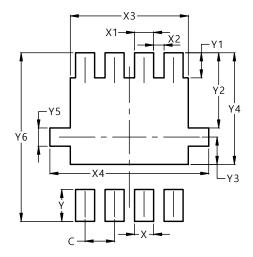


PowerDI3333-8 (SWP)						
(Type UX)						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	_	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
Х3	2.600		
X4	3.500		
Υ	0.700		
Y1	0.550		
Y2	1.650		
Y3	0.600		
Y4	2.450		
Y5	0.400		
Y6	3.700		



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